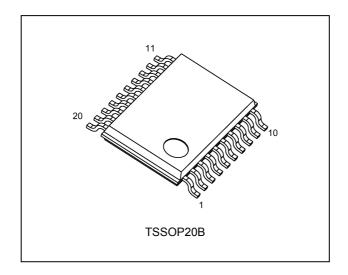
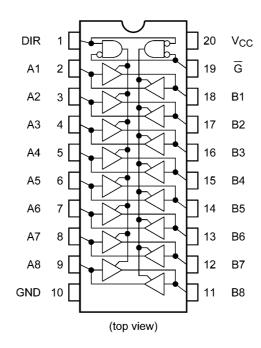


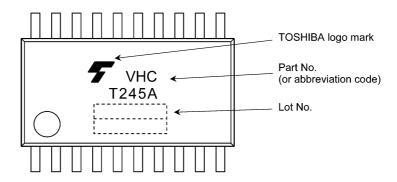
## 4. Packaging



# 5. Pin Assignment

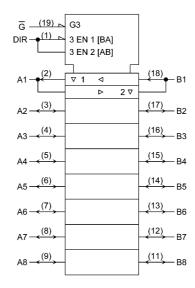


## 6. Marking





## 7. IEC Logic Symbol



#### 8. Truth Table

Input G	Input DIR	A BUS	B BUS	Output
L	L	Output	Input	A = B
L	Н	Input	Output	B = A
Н	Х	Z	Z	Z

X: Don't care

Z: High impedance

## 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage(DIR, $\overline{G}$ )	V <sub>IN</sub>		-0.5 to 7.0	V
Bus I/O voltage	V <sub>I/O</sub>	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to $V_{CC}$ + 0.5	V
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	I <sub>OK</sub>	(Note 3)	±20	mA
Output current	I <sub>OUT</sub>		±25	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±75	mA
Power dissipation	P <sub>D</sub>	(Note 4)	180	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in off-state

Note 2: High or low state. I<sub>OUT</sub> absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND, V<sub>OUT</sub> > V<sub>CC</sub>

Note 4: 180 mW in the range of  $T_a$  = -40 to 85 °C. From  $T_a$  = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.



## 10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		4.5 to 5.5	V
Input voltage(DIR, $\overline{G}$ )	V <sub>IN</sub>		0 to 5.5	V
Bus I/O voltage	V <sub>I/O</sub>	(Note 1)	0 to 5.5	V
		(Note 2)	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>		-40 to 125	°C
Input rise and fall times	dt/dv	·	0 to 20	ns/V

Note: The operating ranges are required to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either  $V_{CC}$  or GND. Please connect both bus inputs and the bus outputs with  $V_{CC}$  or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

Note 1: Output in off-state Note 2: High or low state

#### 11. Electrical Characteristics

## 11.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		4.5 to 5.5	2.0	_	_	V
Low-level input voltage	V <sub>IL</sub>	_		4.5 to 5.5	_	_	0.8	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	4.5	4.4	4.5	_	V
			I <sub>OH</sub> = -8 mA	4.5	3.94	_		
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	4.5	_	0.0	0.1	V
			I <sub>OL</sub> = 8 mA	4.5	_	_	0.36	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	_	±0.25	μΑ
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	-	_	±0.1	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	4.0	μА
Quiescent supply current	I <sub>CCT</sub>	Per input: V <sub>IN</sub> = 3.4 V , other input: V <sub>CC</sub> or GND		5.5	_	_	1.35	mA
Output leakage current (Power-OFF)	I <sub>OPD</sub>	V <sub>OUT</sub> = 5.5 V		0	_	_	0.5	μА

## 11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		4.5 to 5.5	2.0	_	V
Low-level input voltage	V <sub>IL</sub>	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	4.5	4.4	_	V
			I <sub>OH</sub> = -8 mA	4.5	3.80	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	4.5	_	0.1	V
			I <sub>OL</sub> = 8 mA	4.5	_	0.44	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	±2.50	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±1.0	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	40.0	μА
Quiescent supply current	I <sub>CCT</sub>	Per input: V <sub>IN</sub> = 3.4 V, other input: V <sub>CC</sub> or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I <sub>OPD</sub>	V <sub>OUT</sub> = 5.5 V		0	_	5.0	μА



# 11.3. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

Characteristics	Symbol	Test Conditio	n	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		4.5 to 5.5	2.0	_	V
Low-level input voltage	V <sub>IL</sub>	_		4.5 to 5.5		0.8	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	4.5	4.4	_	V
			$I_{OH}$ = -8 mA	4.5	3.70	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	4.5	_	0.1	V
			I <sub>OL</sub> = 8 mA	4.5	_	0.55	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	±10.0	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±2.0	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	80.0	μА
Quiescent supply current	I <sub>CCT</sub>	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I <sub>OPD</sub>	V <sub>OUT</sub> = 5.5 V		0	_	±20.0	μА



## 11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$5.0 \pm 0.5$	15	_	4.9	7.7	ns
					50	1	5.4	8.7	
3-state output enable time	$t_{PZL}, t_{PZH}$		$R_L = 1 k\Omega$	$5.0 \pm 0.5$	15		9.4	13.8	ns
					50	_	9.9	14.8	
3-state output disable time	$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$5.0\pm0.5$	50	-	10.1	15.4	ns
Output skew	$t_{osLH}, t_{osHL}$	(Note 1)	_	$5.0 \pm 0.5$	50		_	1.0	ns
Input capacitance	C <sub>IN</sub>		DIR, G			_	4	10	pF
Bus I/O capacitance	C <sub>I/O</sub>		A <sub>n</sub> , B <sub>n</sub>				13	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 2)	_				16		pF

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m - t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m - t_{PHL}n|$ )

Note 2:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC}(opr) = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$  (per bit)

# 11.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$5.0 \pm 0.5$	15	1.0	8.5	ns
					50	1.0	9.5	
3-state output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		$R_L = 1 k\Omega$	5.0 ± 0.5	15	1.0	15.0	ns
					50	1.0	16.0	
3-state output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>		$R_L = 1 k\Omega$	$5.0 \pm 0.5$	50	1.0	16.5	ns
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$5.0\pm0.5$	50	_	1.0	ns
Input capacitance	C <sub>IN</sub>		DIR, G	·		_	10	pF

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 

# 11.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$5.0 \pm 0.5$	15	1.0	10.0	ns
					50	1.0	11.0	
3-state output enable time	$t_{PZL}, t_{PZH}$		$R_L = 1 k\Omega$	$5.0 \pm 0.5$	15	1.0	17.0	ns
					50	1.0	17.5	
3-state output disable time	$t_{PLZ}, t_{PHZ}$		$R_L = 1 \text{ k}\Omega$	$5.0\pm0.5$	50	1.0	18.0	ns
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$5.0\pm0.5$	50		1.0	ns
Input capacitance	C <sub>IN</sub>		DIR, G		·	_	10	pF

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m - t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m - t_{PHL}n|$ )

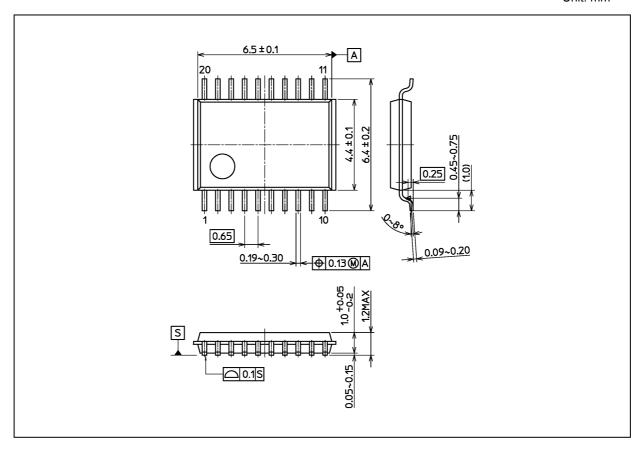
## 11.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	1.1	1.5	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-1.1	-1.5	V
Minimum high-level dynamic input voltage	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0		2.0	V
Maximum low-level dynamic input voltage	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0	_	0.8	V



## **Package Dimensions**

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	



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